

Environmental dielectric screening effect on exciton transition energies in single-walled carbon nanotubes

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Abstract

Environmental dielectric screening effect on exciton transition energies in single-walled carbon nanotubes (SWNTs) have been studied quantitatively in the range of dielectric constant from 1.0 to 37 by immersing SWNTs bridging over trenches in various organic solvents by means of photoluminescence and the excitation spectroscopies. With increasing environmental dielectric constant (ϵ_{env}), both of E_{11} and E_{22} showed redshift by several tens meV and a tendency to saturate at a $\epsilon_{\text{env}} \sim 5$ without indicating significant (n,m) dependence. The redshifts can be explained by dielectric screening of electron-electron repulsion interaction. The ϵ_{env} dependence of E_{11} and E_{22} can be expressed by a simple empirical equation with power law of ϵ_{env} , $E_{ii} = E_{ii}^{\infty} + A\epsilon_{\text{env}}^{-\alpha}$. We also immersed a sample in sodium-dodecyl-sulfate (SDS) solution to investigate effects of wrapping SWNTs with surfactant. The resultant E_{11} and E_{22} , which well-agree with Weisman's data [Nano Lett. **3**, 1235 (2003)], are close to those of ϵ_{env} of 2. However, in addition to the shift due to dielectric screening, another shift was observed so as $(2n+m)$ -family patterns spread more widely similar to uniaxial-stress-induced shift.

I. INTRODUCTION

Optical spectroscopies of single-walled carbon nanotubes (SWNTs) have received increasing attention, not only for assigning the chiral vector, (n,m) , of the SWNTs¹⁻⁴ but also to study the physics of the one-dimensional excitons.⁵⁻⁸ Especially, photoluminescence (PL) and the excitation spectroscopies are the most widely used for characterizing SWNTs with resonant Raman scattering spectroscopy. Two-photon absorption spectroscopy⁶ and Rayleigh scattering spectroscopy combined with TEM or SWM observation⁷ are also powerful techniques to investigate excitonic states of SWNTs and bundle effect.

Recently, environmental effect is one of the most focused topics on the optical properties of SWNTs.⁹⁻¹⁵ It has been known that the optical transition energies vary depending on the kind of surrounding surfactant used to individualize SWNTs.^{9,13} Lefebvre *et al.* have reported the optical transition energies of SWNTs bridging between two micro-pillars fabricated on a Si wafer show a blueshift as compared to the SDS-wrapped SWNTs.¹² We have also compared air-suspended SWNTs grown on a quartz substrate with grating structure to SDS-wrapped SWNTs, and shown that the energy differences between air-suspended and SDS-wrapped SWNTs depend on (n,m) , especially on chiral angle and on type of SWNTs, type-I ($2n + m \bmod 3 = 1$) or type-II ($2n + m \bmod 3 = 2$).¹⁵ These energy variation due to environmental condition has been thought to be produced by the difference in the dielectric constant of the surrounding materials. The energy of the many-body Coulomb interactions between carriers depends on the environmental dielectric constant (ϵ_{env}) because the electric force lines contributing to the Coulomb interactions pass through the matrix as well as the inside of the SWNT.^{16,17} Note that environmental effect is caused not only by the dielectric screening of Coulomb interactions but also by chemical^{13,14} and mechanical conditions.¹⁸ Finnie *et al.* has reported that gas adsorption affect emission energy of SWNTs.¹⁴

The detailed investigations about the environmental effect is still not enough in spite of the importance in understanding the optical properties of SWNTs. The quantitative and separate investigations are necessary to understand contributions of various environmental factors. In this study, we have focused on the dielectric screening effect, which has been quantitatively investigated by immersing the SWNTs grown over trenches into various liquids with different ϵ_{env} from 1.9 to 37 by means of photoluminescence and the excitation spectroscopies.

II. EXPERIMENTAL

For the study on environmental effects, the SWNTs grown between two micro-pillars^{12,19} or over trench^{15,20} are suitable because the environmental condition can be controlled intentionally. The sample used in this work is SWNTs grown on a quartz substrate with periodic trenches as shown in Fig. 1. Both the period and depth of the trenches are 2 μm . The trenches were formed by photolithography, Al-metal evaporation and lift-off, and subsequent reactive-ion etching of the quartz with the Al mask. The SWNTs were grown by alcohol catalytic chemical vapor deposition²¹ at 750°C for 10 s after spin coating of water solution of Co acetate. By optimizing the growth condition, isolated bridging SWNTs can be formed over the trenches. The density of the SWNTs was $\sim 0.2 \mu\text{m}^{-1}$ along the direction of the trench. Such low-density isolated SWNTs were necessary to observe luminescence when the sample was immersed in liquids. On the other hand, in case of a sample with relatively high-density SWNTs as $\sim 2 \mu\text{m}^{-1}$, PL intensity was degraded by immersing in liquids even though strong PL was obtained in air. This is probably because the SWNTs form bundles with neighbors in immersing in liquids in the case of the sample with high-density SWNTs.

The sample was mounted in a vessel with a quartz window, and immersed in various organic solvents with ϵ_{env} from 1.9 to 37 (see Table I). We also immersed a sample in 1-wt% D₂O solution of sodium-dodecyl-sulfate (SDS) to investigate the effect of wrapping with surfactant molecules. PL and the excitation spectra were measured using a home-made facility consisting of a tunable continuous-wave Ti/Sapphire laser (710~850 nm), a monochromator with a focal length of 25 cm, and a liquid-N₂-cooled InGaAs photomultiplier tube (1000~1600 nm). The excitation wavelength was monitored by a laser wavelength meter. The diameter of laser spot on the sample surface was ~ 1 mm, so that an ensemble of many SWNTs was detected.

III. RESULTS AND DISCUSSION

Figure 2 shows PL maps of SWNTs (a)~(g) in various organic solvents with different ϵ_{env} and (h) in SDS solution. By immersing the sample in the organic solvents, the emission and excitation peaks, which respectively correspond to E_{11} and E_{22} , showed redshifts and spectral broadening. In the PL map measured in SDS solution²², the peak positions well-

agree with those of Weisman’s empirical Kataura plot for SDS-wrapped SWNTs represented by crosses³.

The E_{22} - E_{11} plots in air ($\epsilon_{\text{env}} = 1.0$), hexane (1.9), chloroform (4.8), and SDS solution are shown in Fig. 3. Both of E_{11} and E_{22} showed redshifts with increasing ϵ_{env} without significant (n,m) dependence. The amounts of the redshifts are 33~49 meV for E_{11} and 26~30 meV for E_{22} . The redshift with increasing ϵ_{env} is consistent with the theoretical work by Ando.¹⁶ The optical transition energy in SWNTs is given by a summation of the bandgap and the exciton binding energy. When the ϵ_{env} increases, the Coulomb interaction is enhanced and the exciton binding energy decreases. This leads to a blueshift of the optical transition energy in the SWNT. It should be noted that the bandgap is renormalized by the electron-electron repulsion interaction, and consequently the change in the ϵ_{env} affects not only the exciton binding energy but also the bandgap. According to theoretical works,^{16,24} the electron-electron repulsion energy is larger in magnitude than the exciton binding energy. Therefore, if we consider the both energies show similar dependence on the ϵ_{env} , the decrease in the electron-electron repulsion energy exceeds the decrease in the exciton binding energy when the ϵ_{env} increases. This results in the redshift of optical transition energies. The redshifts observed in the present experiment are attributed to the decrease in the repulsion energy of the electron-electron interaction with the increase in the ϵ_{env} . Note that even though the redshift with increasing ϵ_{env} is consistent with the theoretical works, the amount of the redshifts is much smaller than the calculations. This is probably because in the present experiments the ϵ_{env} only outside of the SWNTs was varied whereas the theoretical works used a dielectric constant for whole system.

E_{11} and E_{22} are plotted as a function of ϵ_{env} in Fig. 4. The energy shifts show a tendency to saturate at $\epsilon_{\text{env}} \sim 5$. The energy variations can be fitted to an empirical expression with power law of ϵ_{env} ,

$$E_{\text{ii}} = E_{\text{ii}}^{\infty} + A\epsilon_{\text{env}}^{-\alpha} \quad (1)$$

where E_{ii}^{∞} corresponds to transition energy when ϵ_{env} is infinity, A corresponds to the maximum value of the energy change by ϵ_{env} , and α is a fitting parameter. A and α are 38 meV and 1.9 for E_{11} , and 29 meV and 1.6 for E_{22} , respectively, in average. Perebeinos *et al.* have reported power law scaling for excitonic binding energy by dielectric constant, where scaling factor α is estimated to be ~ 1.4 in the range of $\epsilon > 4$.¹⁷ Although the power law expression of Eq. 1 is quite similar to the Perebeinos’s scaling law for exciton binding energy, present

empirical expression is attributed to the scaling of electron-electron repulsion energy by ϵ_{env} rather than exciton (electron-hole) binding energy as described above. Quite recently, such power-law-like-downshift of optical transition energy with ϵ_{env} has been obtained by theoretical calculation based on tight-binding model.²³

We have previously pointed out that the E_{11} and E_{22} varies depending on (n,m) , in particular on chiral angle and on the type of SWNTs (type-I or type-II), comparing those of SDS-wrapped SWNTs to those of air-suspended SWNTs. The same behavior occurred by immersing a sample in SDS solution as shown in Fig. 2(h). Most of E_{11} and E_{22} of SDS-wrapped SWNTs show redshift, except for E_{22} of near-zigzag type-II SWNTs which show blueshift as compared to those in air. This behavior is inconsistent with the results of ϵ_{env} dependence as described above, in which (n,m) dependence is not significant. Comparing the PL maps in SDS solution to those in organic solvents as shown in Fig. 3, the equivalent ϵ_{env} of SDS wrapping SWNTs would be ~ 2 . In addition to the shift due to the dielectric screening, the peak positions of SDS-wrapped SWNTs shift so as the $(2n+m)$ -family patterns spread more widely. This suggest that wrapping with SDS has another effect on top of the dielectric screening effect. The behavior of the additional shifts is similar to the shift induced by uniaxial stress reported by Arnold *et al.*¹⁸ At present, it is still remained issue whether such uniaxial strain is induced to SWNTs by wrapping with surfactants or not. Charging effect due to SDS which is one of anionic surfactants should also be considered. Further study is necessary to understand the effects of surfactants on optical transition energy of SWNTs.

Finally, we note the broadening of PL spectra in liquids. The representative spectra are shown in Fig. 5. The peaks show the broadening in addition to the redshift with increasing ϵ_{env} . The linewidth increased from 23 meV in air to 40 meV in acetonitrile for (9,7) SWNTs. This linewidth broadening is probably attributed to inhomogeneous broadening due to local fluctuation of ϵ_{env} in nano-dimension. The dielectric constants we used in Table I are macroscopic value. In the small dimension such as exciton diameter of a few nm²⁴, the size of molecules of the organic solvents would be considerable so that the local ϵ_{env} would fluctuate depending on the number and orientation of the organic molecules. This would result in inhomogeneous broadening of PL spectrum.

IV. SUMMARY

In summary, dielectric screening effect due to environment around SWNTs on exciton transition energies in the SWNTs have been studied quantitatively by means of PL and the excitation spectroscopies. We varied the ϵ_{env} from 1.0 to 37 by immersing the samples with SWNTs bridging over trenches in various organic solvents with different ϵ_{env} s. With increasing ϵ_{env} , both of E_{11} and E_{22} showed redshift by 33~49 meV for E_{11} and 26~30 meV for E_{22} and a tendency to saturate at $\epsilon_{\text{env}} \sim 5$, without significant (n,m) dependence. The redshifts can be explained by dielectric screening of electron-electron repulsion energy. The ϵ_{env} dependence of E_{11} and E_{22} were expressed by a simple empirical equation with power law of ϵ_{env} . The equivalent ϵ_{env} of SDS wrapping SWNTs were estimated to be ~ 2 . It was suggested that the effect of wrapping SWNTs with SDS was not only dielectric screening effect but also another effect which caused the energy shift like uniaxial-stress-induced shift.

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TABLE I: ϵ_{env} of air and various liquids used in this study.

solvent	ϵ_{env}
air	1.0
hexane	1.9
chloroform	4.8
ethyl acetate	6.0
dichloromethane	9.0
acetone	21
acetonitrile	37

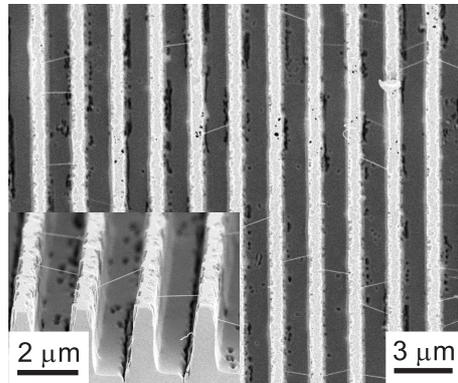


FIG. 1: Plan-view and bird-view (inset) SEM images of SWNTs bridging over trenches on a quartz substrate. Pt thin film was deposited on the sample in order to avoid charge up of the insulating substrate and to observe individual SWNTs. By optimizing growth condition, individual SWNTs can be obtained.

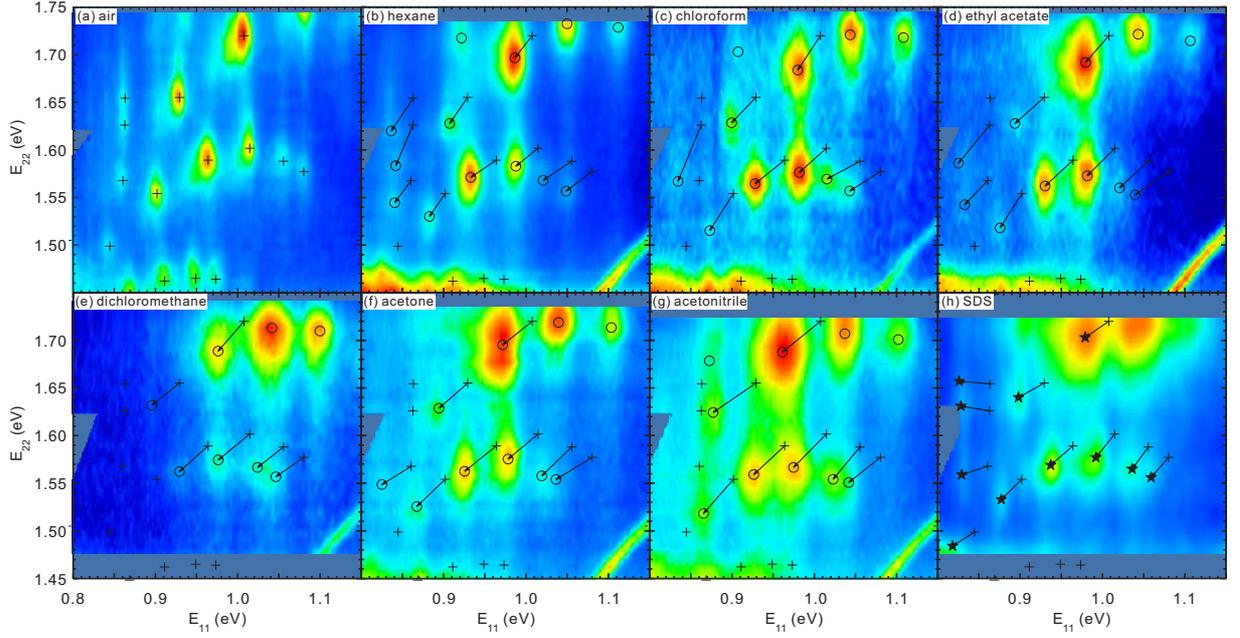


FIG. 2: PL contour maps for SWNTs; (a) in air ($\epsilon_{\text{env}} = 1.0$), (b) hexane ($\epsilon_{\text{env}} = 1.9$), (c) chloroform ($\epsilon_{\text{env}} = 4.8$), (d) ethyl acetate ($\epsilon_{\text{env}} = 6.0$), (e) dichloromethane ($\epsilon_{\text{env}} = 9.0$), (f) acetone ($\epsilon_{\text{env}} = 20.7$), and (g) acetonitrile ($\epsilon_{\text{env}} = 37.5$), and (h) SDS/D₂O solution. The crosses and open circles represent peak positions in air and in the liquid. In (h), stars represent the peak positions of SDS-wrapped SWNTs reported by Weisman *et al*³. The PL intensity color schemes are linear, but different scaling factors were used for each maps. The emission and excitation maxima correspond to E_{11} and E_{22} , respectively.

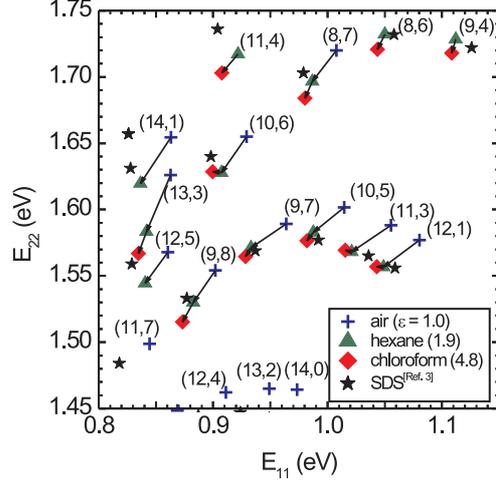


FIG. 3: E_{22} versus E_{11} plots in air ($\epsilon_{\text{env}} = 1.0$), hexane ($\epsilon_{\text{env}} = 1.9$), chloroform ($\epsilon_{\text{env}} = 4.8$). The stars represent the peak positions of SDS-wrapped SWNTs³. Both E_{11} and E_{22} show redshifts with increasing ϵ_{env} with a small (n,m) dependence. The peak positions of SDS-wrapped SWNTs deviate from the line of dielectric screening effect.

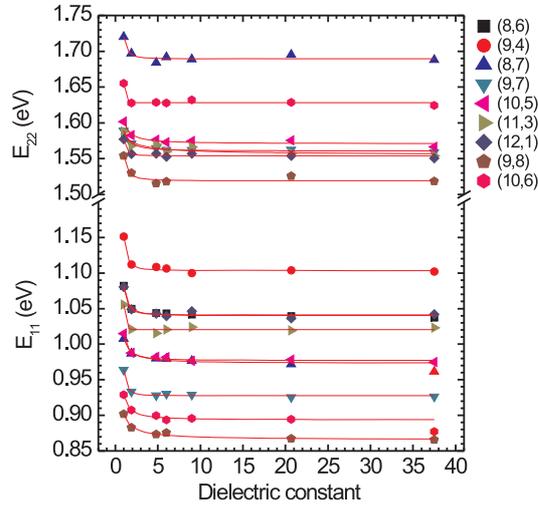


FIG. 4: ϵ_{env} dependences of E_{11} and E_{22} of various (n,m) SWNTs. The solid lines are fitting curves given by an empirical expression with power law of ϵ_{env} .

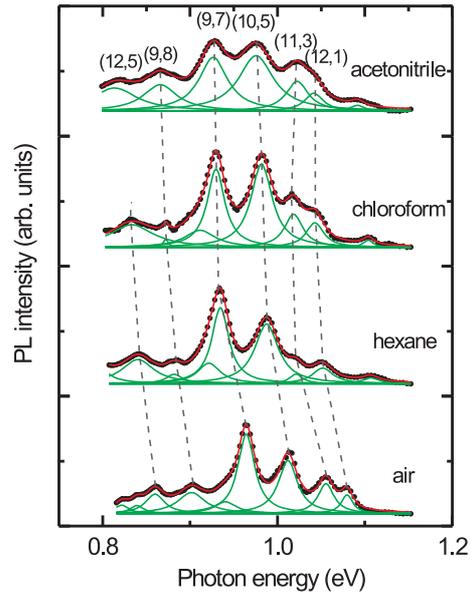


FIG. 5: PL spectra in various liquids. With increasing ϵ_{env} , the emission spectra show linewidth broadening in addition to redshift.